

## Automotive IPD Series

# 2ch High Side Switch

### BV2HM050EFV-C

#### General Description

BV2HM050EFV-C is a 2ch high side switch for automotive application. It has a built in hiccup mode overcurrent protection function, thermal shutdown protection function, open load detection function, under voltage lockout function. It is equipped with diagnostic output function for abnormality detection.

#### Features

- AEC-Q100 Qualified<sup>(Note 1)</sup>
- Built in Hiccup Mode Overcurrent Protection Function (OCP)
- Built-in Thermal Shutdown Protection Function (TSD)
- Built-in Open Load Detection Function (OLD)
- Built-in Under Voltage Lockout Function (UVLO)
- Low On-Resistance  $R_{ON} = 50\text{ m}\Omega$  (Typ)
- Monolithic Power Management IC with the Control Block (CMOS) and Power MOSFET Mounted on a Single Chip

(Note 1) Grade1

#### Key Specifications

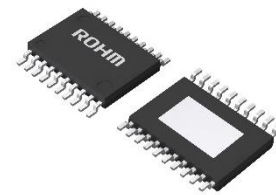
- Power Supply Voltage Operating Range: 6 V to 28 V
- ON-Resistance ( $T_j = 25\text{ }^\circ\text{C}$ ): 50 m $\Omega$  (Typ)
- Overcurrent Value: 5 A (Min)
- Standby Current ( $T_j = 25\text{ }^\circ\text{C}$ ): 0.5  $\mu\text{A}$  (Max)
- Active Clamp Energy ( $T_j = 25\text{ }^\circ\text{C}$ ): 140 mJ

#### Package

HTSSOP-B20

#### W (Typ) x D (Typ) x H (Max)

6.5 mm x 6.4 mm x 1.0 mm



HTSSOP-B20

#### Application

- Resistance Load, Inductance Load and Capacitance Load for Automotive Application

#### Typical Application Circuit

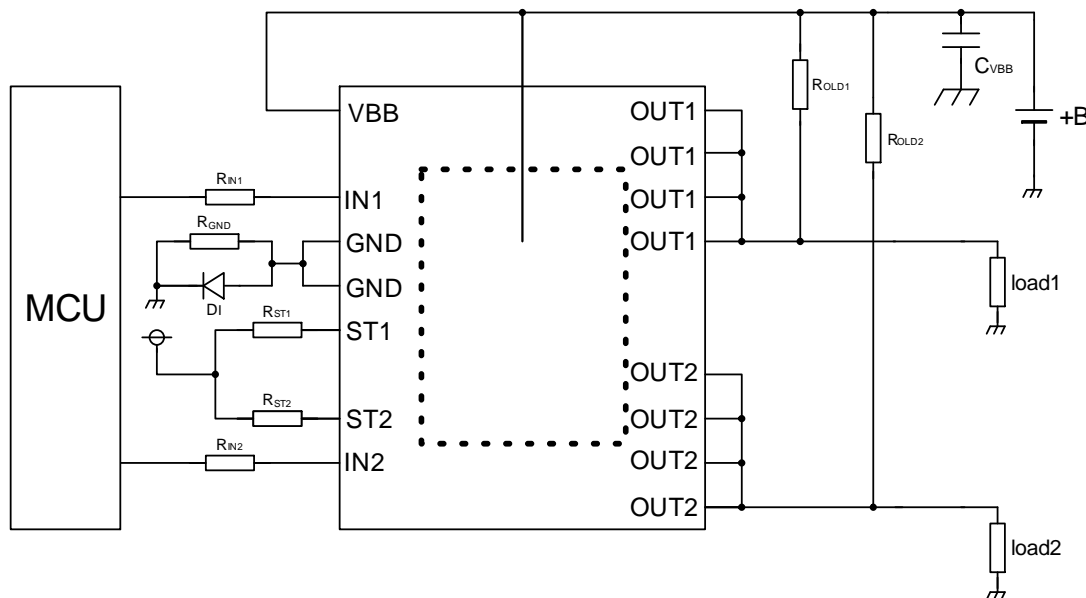


Figure 1. Application Circuit



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## Pin Configuration

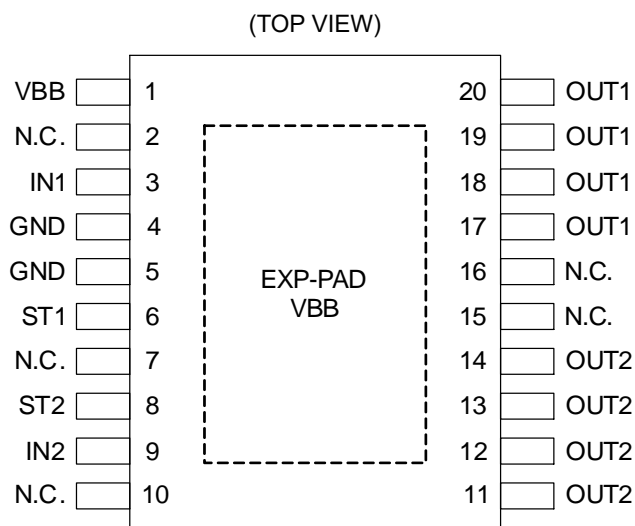


Figure 2. Pin Configuration

## Pin Description

Pin No.	Pin Name	Function
1	VBB	Power input pin, switch input pin
2	N.C.	-
3	IN1	Channel 1 Input pin. Pull-down resistor is connected internally.
4	GND	Ground pin
5	GND	Ground pin
6	ST1	Channel 1 Self-diagnostic output pin
7	N.C.	-
8	ST2	Channel 2 Self-diagnostic output pin
9	IN2	Channel 2 Input pin. Pull-down resistor is connected internally.
10	N.C.	-
11 to 14	OUT2	Channel 2 Switch output pin
15	N.C.	-
16	N.C.	-
17 to 20	OUT1	Channel 1 Switch output pin
EXP-PAD	VBB	Power input pin, switch input pin



Block Diagram

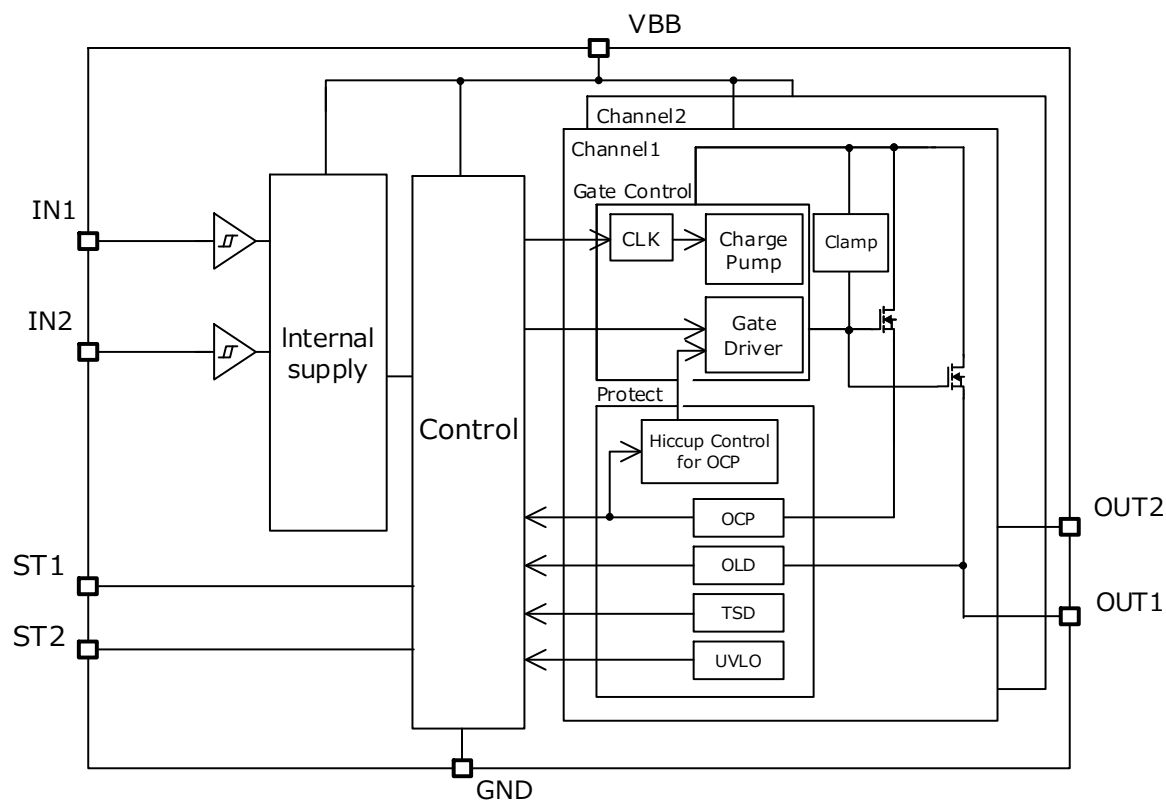


Figure 3. Block Diagram

Definition

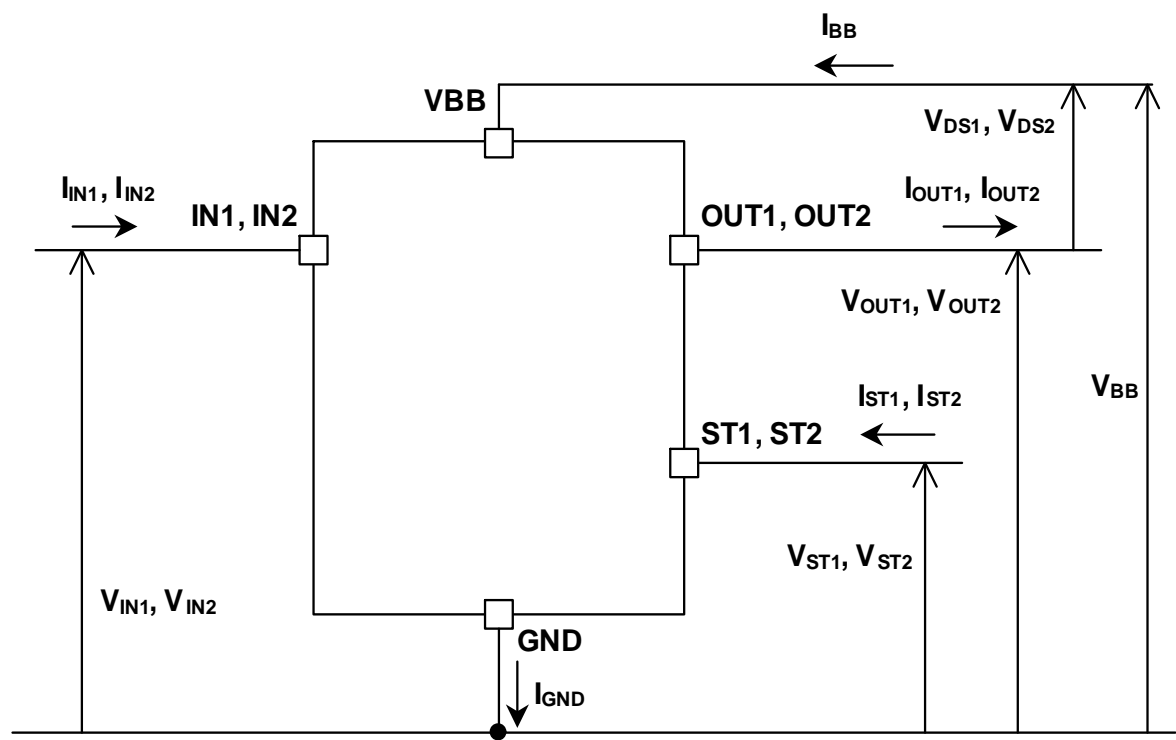


Figure 4. Voltage and Current Definition



## Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
VBB - OUT Voltage	V <sub>DS</sub>	-0.3 to Internal clamp <sup>(Note 1)</sup>	V
Power Supply Voltage	V <sub>BB</sub>	-0.3 to +40	V
Input Voltage	V <sub>IN1</sub> , V <sub>IN2</sub>	-0.3 to +7.0	V
Input Current	I <sub>IN1</sub> , I <sub>IN2</sub>	-2.0 to +2.0	mA
Diagnostic Output Voltage	V <sub>ST1</sub> , V <sub>ST2</sub>	-0.3 to +7.0	V
Output Current	I <sub>OUT1</sub> , I <sub>OUT2</sub>	11.0 (Overcurrent Value I <sub>OC</sub> ) <sup>(Note 2)</sup>	A
Junction Temperature Width	T <sub>j</sub>	-40 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Maximum Junction Temperature	T <sub>jmax</sub>	150	°C
Active Clamp Energy <sup>(Note 3) (Note 4)</sup> (Single Pulse, T <sub>j</sub> = 25 °C)	E <sub>AS</sub>	140	mJ
Active Clamp Energy <sup>(Note 3) (Note 4)</sup> (Single Pulse, T <sub>j</sub> = 150 °C)	E <sub>AS</sub>	65	mJ
Supply Voltage for Short Circuit Protection <sup>(Note 4) (Note 5)</sup>	V <sub>BBLIM</sub>	28	V

(Note 1) Internally limited by output clamp voltage.

(Note 2) When overcurrent flows, output is turned off. (Output self-restarts after a certain time.)

(Note 3) Maximum active clamp energy using Single Pulse of I<sub>OUT(START)</sub> = 2 A and V<sub>BB</sub> = 14 V.

(Note 4) Not 100 % tested.

(Note 5) Maximum power supply voltage that can detect short circuit protection.

**Caution 1:** Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

**Caution 2:** Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

**Caution 3:** When IC turns off with an inductive load, reverse energy is generated. This energy can be calculated by the following equation:

$$E_L = \frac{1}{2} \times L \times I_{OUT(START)}^2 \times \left(1 - \frac{V_{BB}}{V_{BB} - V_{DS}}\right)$$

Where:

L is the inductance of the inductive load.

I<sub>OUT(START)</sub> is the output current at the time of turning off.

The BV2HM050EFV-C integrates the active clamp function to internally absorb the reverse energy E<sub>L</sub> which is generated when the inductive load is turned off. When the active clamp operates, the thermal shutdown function does not work. Decide a load so that the reverse energy E<sub>L</sub> is active clamp energy E<sub>AS</sub> (refer to Figure 5. Active Clamp Energy vs Output Current) or under when inductive load is used.

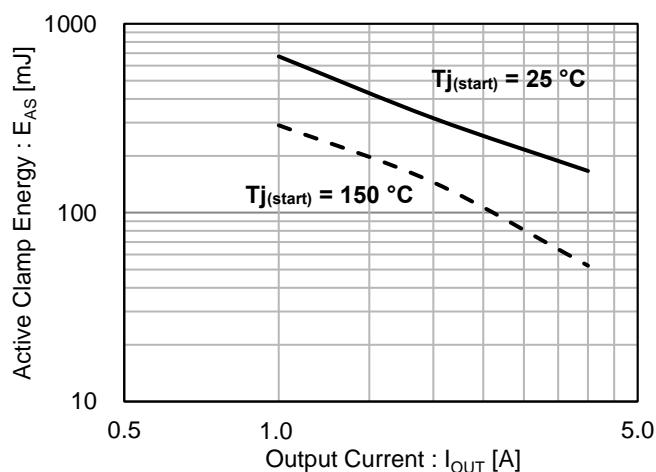


Figure 5. Active Clamp Energy vs Output Current



## Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Operating Power Supply Voltage	$V_{BB}$	6	14	28	V
Operating Temperature	$T_{opr}$	-40	+25	+150	°C
Operating Frequency (Input Voltage 50 % Duty)	$f_{IN}$	-	-	1	kHz

Thermal Resistance<sup>(Note 1)</sup>

Parameter	Symbol	Typ	Unit	Condition
HTSSOP-B20				
Between Junction and Surroundings Temperature Thermal Resistance	$\theta_{JA}$	108.1	°C/W	1s <sup>(Note 2)</sup>
		42.4	°C/W	2s <sup>(Note 3)</sup>
		33.1	°C/W	2s2p <sup>(Note 4)</sup>

(Note 1) The thermal impedance is based on JE5D51-2A (Still-Air) standard. It is used the chip of BV2HM050EFV-C

(Note 2) JE5D51-3 standard FR4 114.3 mm x 76.2 mm x 1.57 mm 1-layer (1s)

(Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.)

(Note 3) JE5D51-5 standard FR4 114.3 mm x 76.2 mm x 1.60 mm 2-layer (2s)

(Top copper foil: ROHM recommended Footprint + wiring to measure

Copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm, copper (top & reverse side) 2 oz.)

(Note 4) JE5D51-5 / -7 standard FR4 114.3 mm x 76.2 mm x 1.60 mm 4-layers (2s2p)

(Top copper foil: ROHM recommended Footprint + wiring to measure

2 inner layers and copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm, copper (top & reverse side / inner layers) 2 oz / 1 oz.)

## ■ PCB Layout 1 layer (1s)

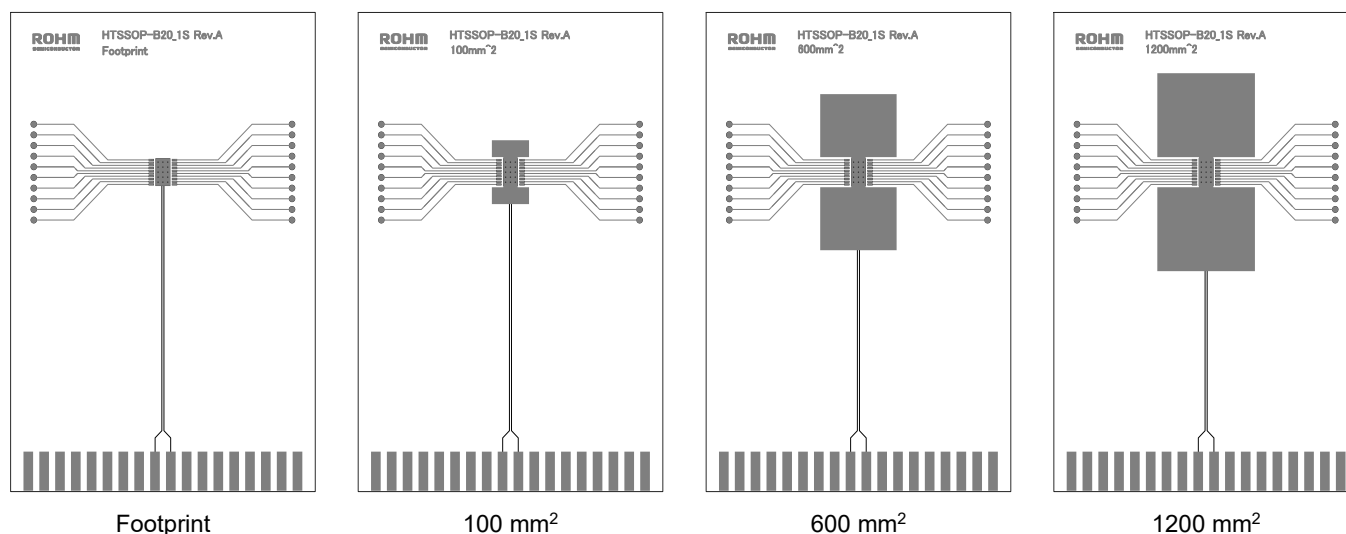


Figure 6. PCB Layout 1 layer (1s)

Dimension	Value
Board finish thickness	1.57 mm
Board dimension	76.2 mm x 114.3 mm
Board material	FR4
Copper thickness	0.070 mm (Cu: 2oz)
Copper foil area	Footprint / 100 mm <sup>2</sup> / 600 mm <sup>2</sup> / 1200 mm <sup>2</sup>



Thermal Resistance – continued

■ PCB Layout 2 layers (2s)

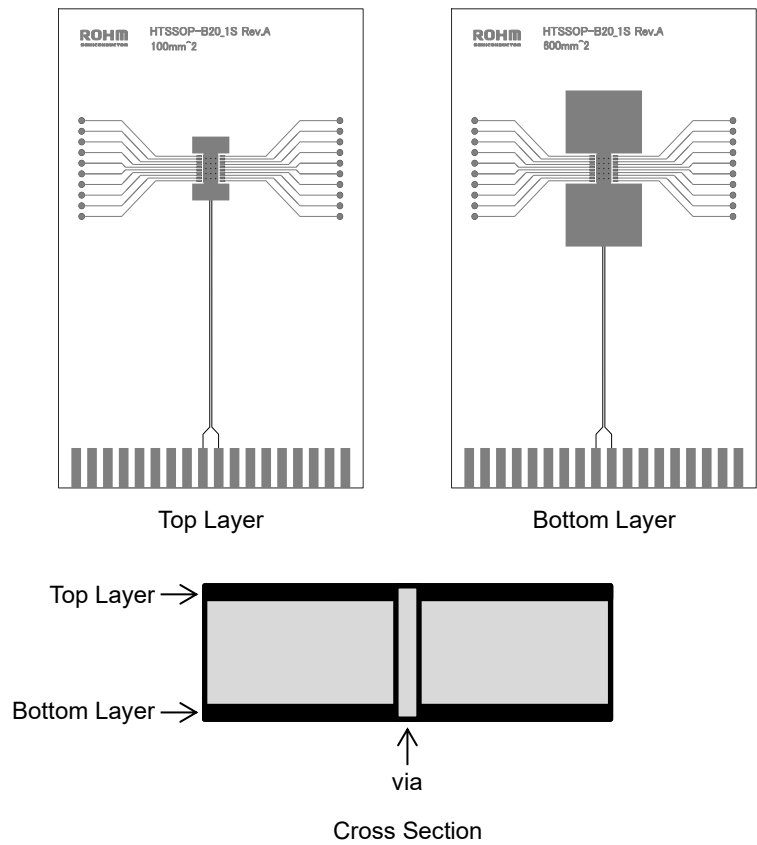


Figure 7. PCB Layout 2 layers (2s)

Dimension	Value
Board finish thickness	1.60 mm
Board dimension	76.2 mm x 114.3 mm
Board material	FR4
Copper thickness (Top / Bottom layers)	0.070 mm (Cu: 1oz + Plating)
Thermal vias separation / diameter	1.2 mm / 0.3 mm



Thermal Resistance – continued

■ PCB Layout 4 layers (2s2p)

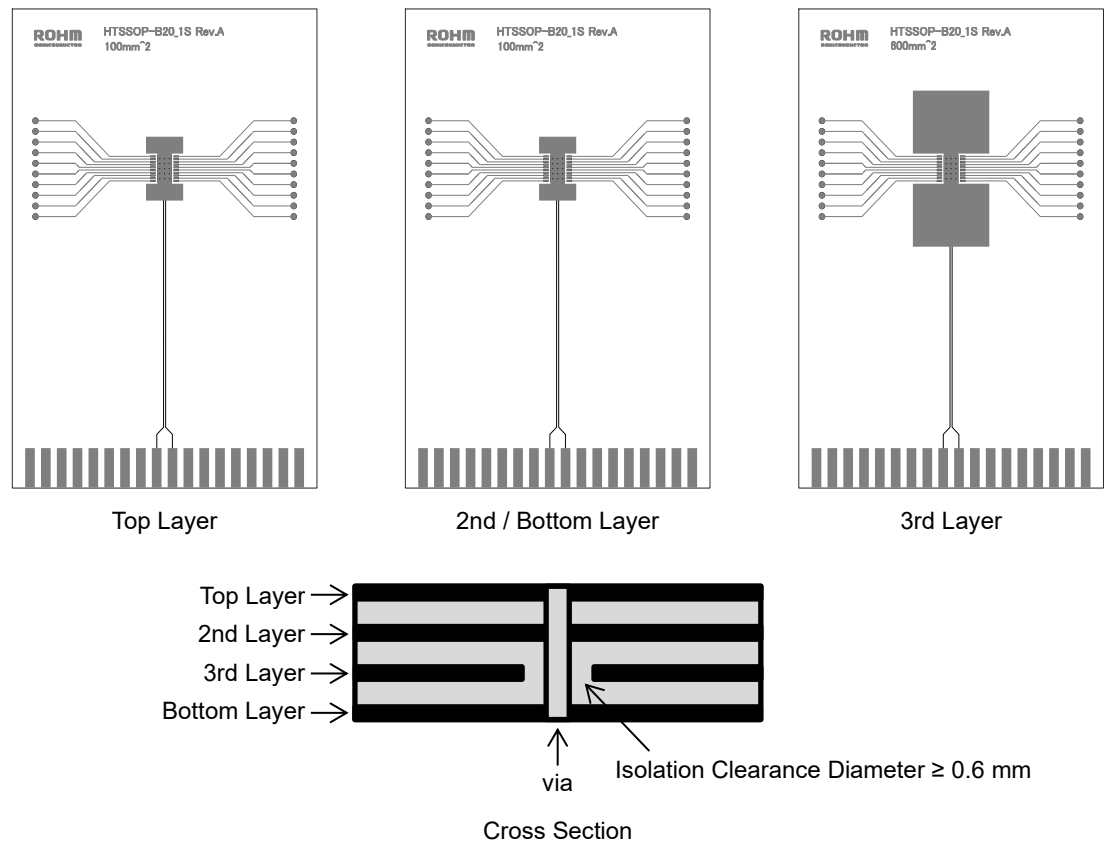


Figure 8. PCB Layout 4 layers (2s2p)

Dimension	Value
Board finish thickness	1.60 mm
Board dimension	76.2 mm x 114.3 mm
Board material	FR4
Copper thickness (Top / Bottom layers)	0.070 mm (Cu: 1oz + Plating)
Copper thickness (Inner layers)	0.035 mm
Thermal vias separation / diameter	1.2 mm / 0.3 mm



Thermal Resistance – continued

■ Transient Thermal Resistance (Single Pulse)

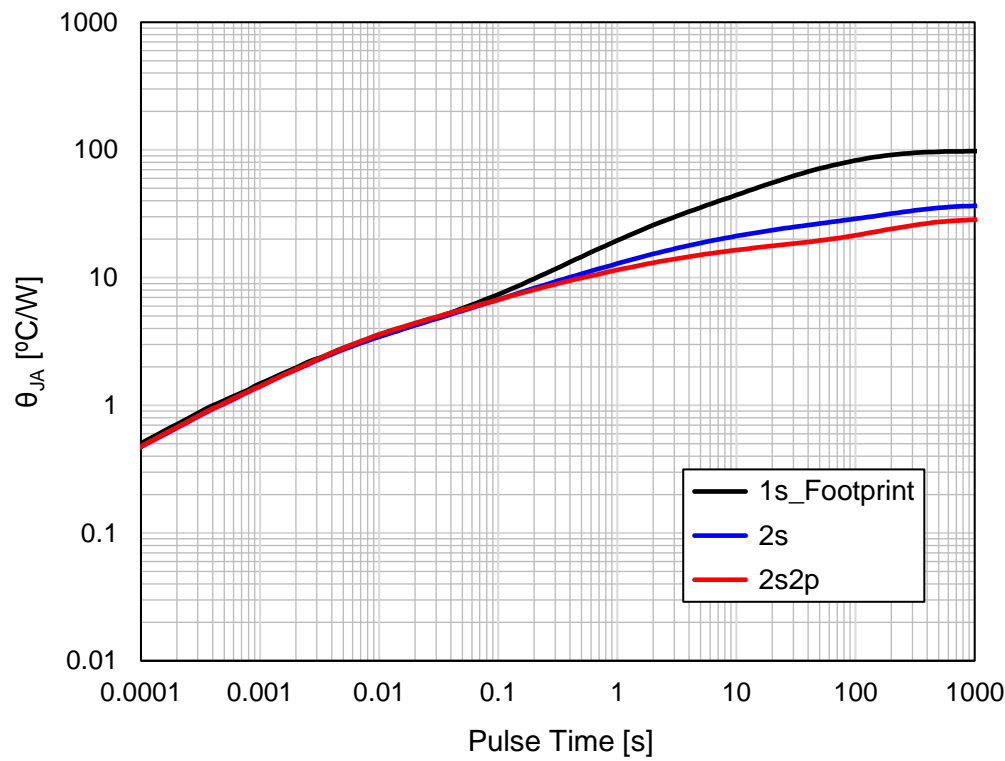


Figure 9. Transient Thermal Resistance

■ Thermal Resistance ( $\theta_{JA}$  vs Copper foil area- 1s)

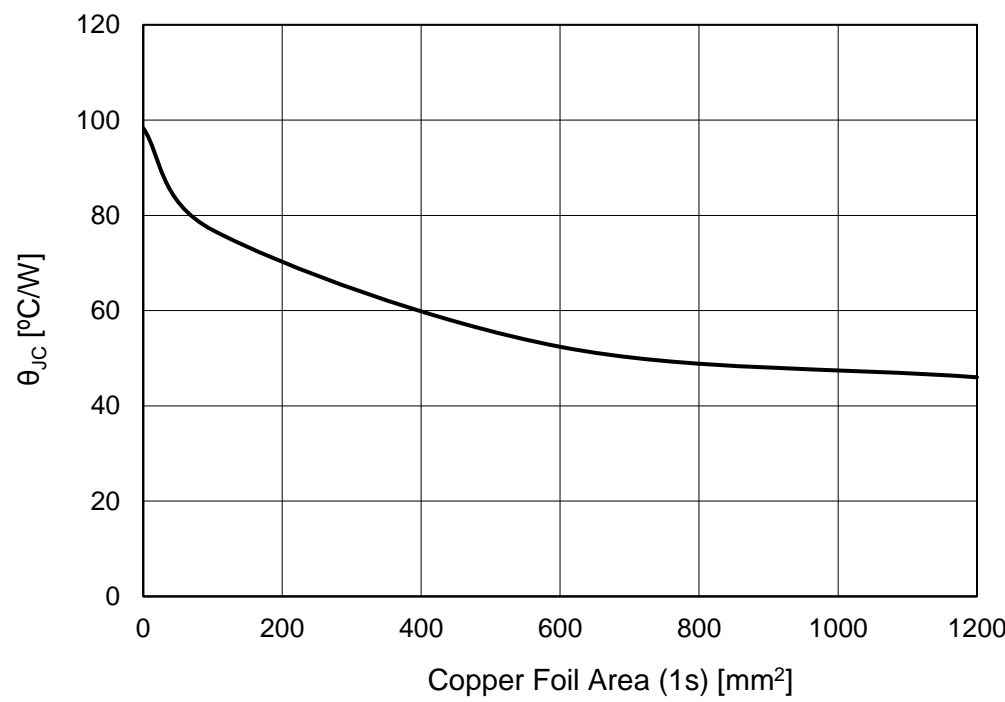


Figure 10. Thermal Resistance



Electrical Characteristics (unless otherwise specified  $V_{BB} = 6\text{ V to }28\text{ V}$ ,  $T_j = -40\text{ }^{\circ}\text{C to }+150\text{ }^{\circ}\text{C}$ )

Parameter	Symbol	Limit			Unit	Conditions
		Min	Typ	Max		
[Power Supply]						
Standby Current	I <sub>BBL1</sub>	-	-	0.5	μA	V <sub>BB</sub> = 14 V, V <sub>IN</sub> = 0 V, V <sub>OUT</sub> = 0 V, T <sub>j</sub> = 25 °C
	I <sub>BBL2</sub>	-	-	20	μA	V <sub>BB</sub> = 14 V, V <sub>IN</sub> = 0 V, V <sub>OUT</sub> = 0 V, T <sub>j</sub> = 150 °C
Operating Current	I <sub>BBH</sub>	-	5	10	mA	V <sub>BB</sub> = 14 V, V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = Open
UVLO Detection Voltage	V <sub>UVLO</sub>	-	-	5.0	V	
UVLO Hysteresis Voltage	V <sub>UVHYS</sub>	-	-	1.0	V	
[Input (V <sub>IN1</sub> , V <sub>IN2</sub> ) ]						
High Level Input Voltage	V <sub>INH</sub>	2.1	-	-	V	
Low Level Input Voltage	V <sub>INL</sub>	-	-	0.9	V	
Input Hysteresis Voltage	V <sub>HYS</sub>	-	0.3	-	V	
High Level Input Current	I <sub>INH</sub>	-	50	150	μA	V <sub>IN</sub> = 5 V
Low Level Input Current	I <sub>INL</sub>	-10	-	+10	μA	V <sub>IN</sub> = 0 V
[Power MOS Output]						
Output ON Resistance	R <sub>ON1</sub>	-	50	65	mΩ	V <sub>BB</sub> = 8 V to 18 V, T <sub>j</sub> = 25 °C
	R <sub>ON2</sub>	-	-	115	mΩ	V <sub>BB</sub> = 8 V to 18 V, T <sub>j</sub> = 150 °C
	R <sub>ON3</sub>	-	-	90	mΩ	V <sub>BB</sub> = 6 V, T <sub>j</sub> = 25 °C
Output Leak Current	I <sub>OUTL1</sub>	-	-	0.5	μA	V <sub>IN</sub> = 0 V, V <sub>OUT</sub> = 0 V, T <sub>j</sub> = 25 °C
	I <sub>OUTL2</sub>	-	-	20	μA	V <sub>IN</sub> = 0 V, V <sub>OUT</sub> = 0 V, T <sub>j</sub> = 150 °C
Output Slew Rate when ON	SR <sub>ON</sub>	0.05	0.20	0.50	V/μs	V <sub>BB</sub> = 14 V, R <sub>L</sub> = 6.5 Ω
Output Slew Rate when OFF	SR <sub>OFF</sub>	0.05	0.20	0.50	V/μs	V <sub>BB</sub> = 14 V, R <sub>L</sub> = 6.5 Ω
Output Propagation Delay Time when ON	t <sub>OUTON</sub>	-	70	160	μs	V <sub>BB</sub> = 14 V, R <sub>L</sub> = 6.5 Ω
Output Propagation Delay Time when OFF	t <sub>OUTOFF</sub>	-	70	160	μs	V <sub>BB</sub> = 14 V, R <sub>L</sub> = 6.5 Ω
Output Clamp Voltage	V <sub>DSCLP</sub>	45	50	55	V	V <sub>IN</sub> = 0 V, I <sub>OUT</sub> = 10 mA
[Diagnostics]						
Diagnostic Output Low Voltage	V <sub>STL</sub>	-	-	0.5	V	I <sub>ST</sub> = 1 mA
Diagnostic Output Leak Current	I <sub>STL</sub>	-	-	10	μA	V <sub>ST</sub> = 5 V
Diagnostic Output Propagation Delay Time when ON	t <sub>STON</sub>	10	50	100	μs	
Diagnostic Output Propagation Delay Time when OFF	t <sub>STOFF</sub>	125	300	500	μs	
[Protection Circuit]						
Overcurrent Value	I <sub>OC</sub>	5	8	11	A	V <sub>OUT</sub> = 0 V
Overcurrent Detection ON Time	t <sub>OCON</sub>	-	10	40	μs	V <sub>OUT</sub> = 0 V
Overcurrent Detection OFF Time	t <sub>OCOFF</sub>	1.0	2.5	4.0	ms	
Open Load Detection Voltage	V <sub>OLD</sub>	2.0	3.0	4.0	V	
Open Load Detection Sink Current	I <sub>OLD</sub>	-	20	60	μA	V <sub>IN</sub> = 0 V, V <sub>OUT</sub> = 5 V
Thermal Shutdown Detection Temperature (Note 1)	T <sub>TSDDET</sub>	160	185	210	°C	
Thermal Shutdown Release Temperature (Note 1)	T <sub>TSDREL</sub>	150	-	-	°C	
Thermal Shutdown Hysteresis Temperature (Note 1)	T <sub>TSDHYS</sub>	-	10	-	°C	

(Note 1) Not 100 % tested.



Typical Performance Curves

(Unless otherwise specified  $V_{BB} = 14\text{ V}$ ,  $V_{IN} = 5\text{ V}$ ,  $T_j = 25\text{ }^{\circ}\text{C}$ )

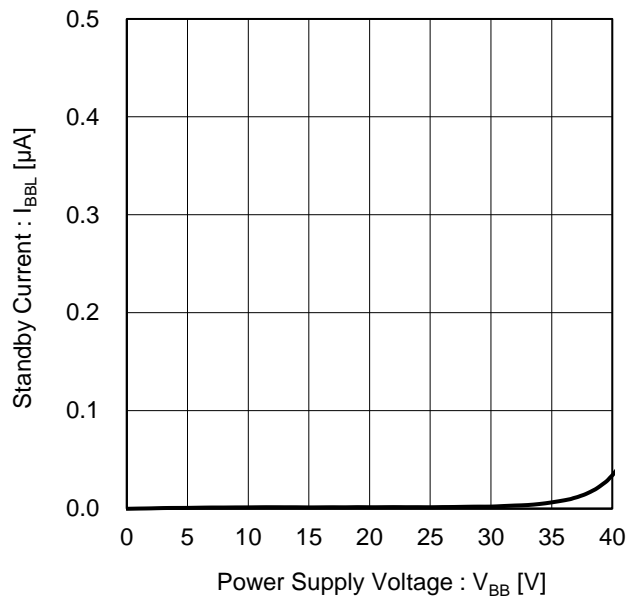


Figure 11. Standby Current vs Power Supply Voltage

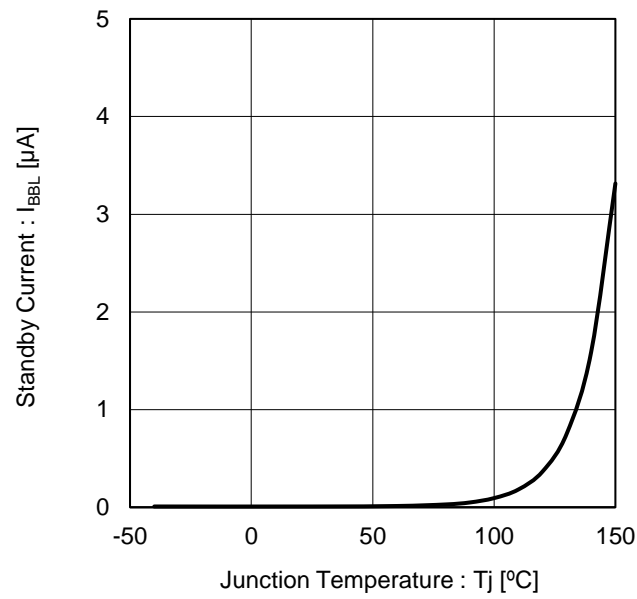


Figure 12. Standby Current vs Junction Temperature

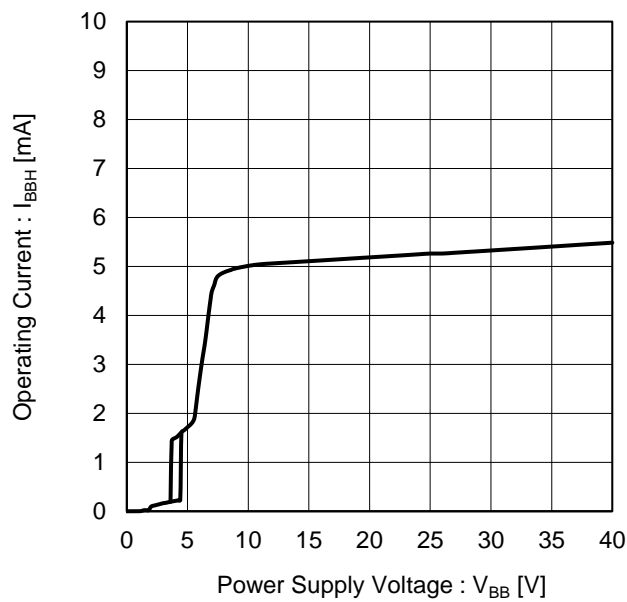


Figure 13. Operating Current vs Power Supply Voltage

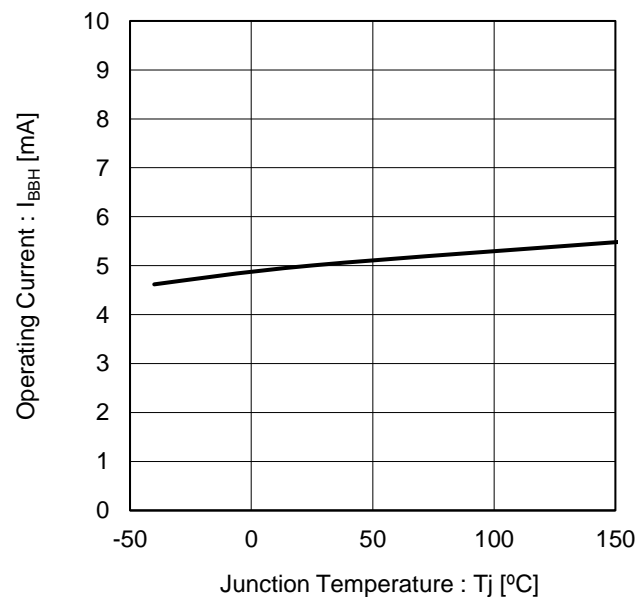


Figure 14. Operating Current vs Junction Temperature



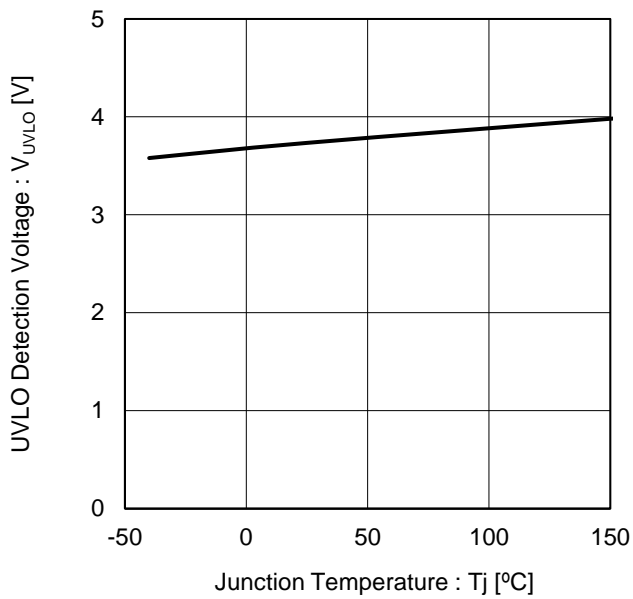
**Typical Performance Curves - continued**(Unless otherwise specified  $V_{BB} = 14\text{ V}$ ,  $V_{IN} = 5\text{ V}$ ,  $T_j = 25\text{ }^{\circ}\text{C}$ )

Figure 15. UVLO Detection Voltage vs Junction Temperature

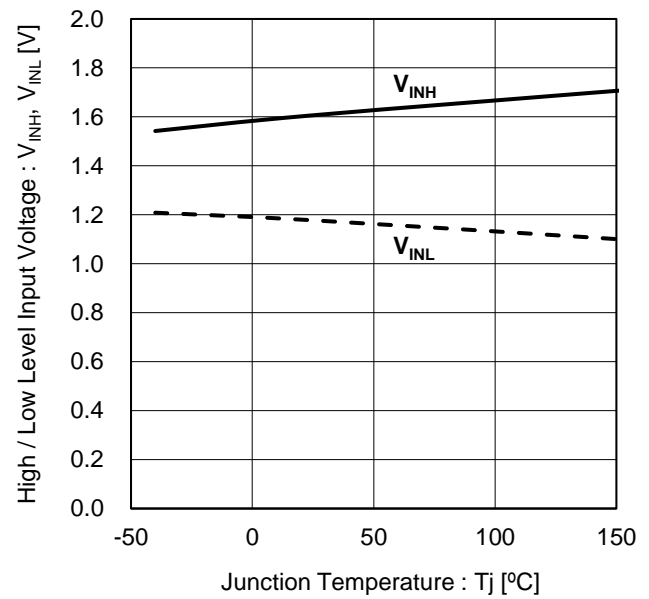


Figure 16. High / Low Level Input Voltage vs Junction Temperature

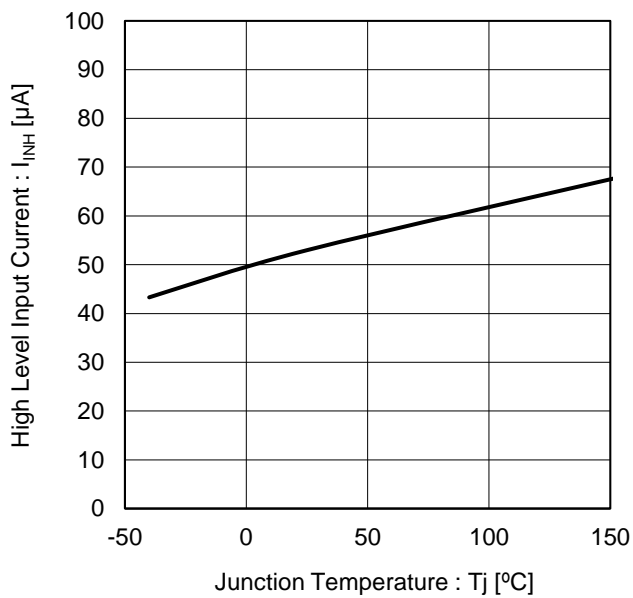


Figure 17. High Level Input Current vs Junction Temperature

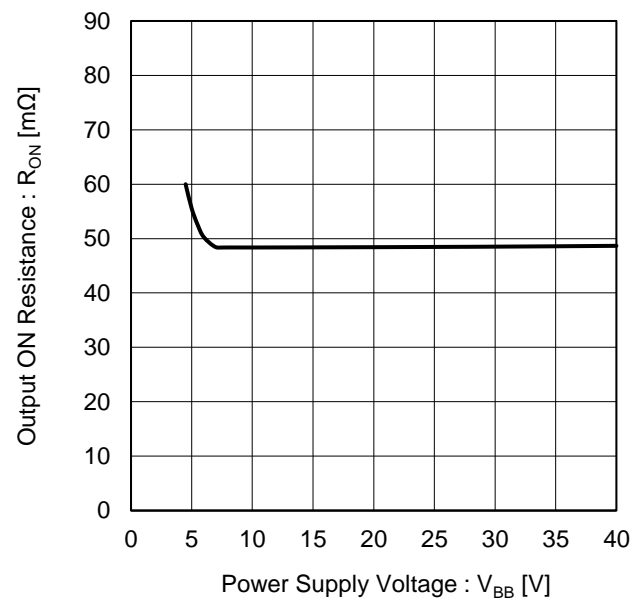


Figure 18. Output ON Resistance vs Power Supply Voltage



## Typical Performance Curves - continued

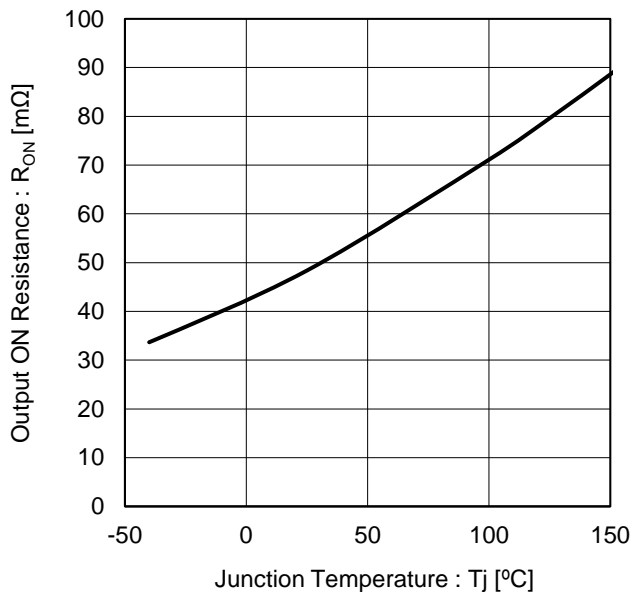
(Unless otherwise specified  $V_{BB} = 14\text{ V}$ ,  $V_{IN} = 5\text{ V}$ ,  $T_j = 25\text{ }^{\circ}\text{C}$ )

Figure 19. Output ON Resistance vs Junction Temperature

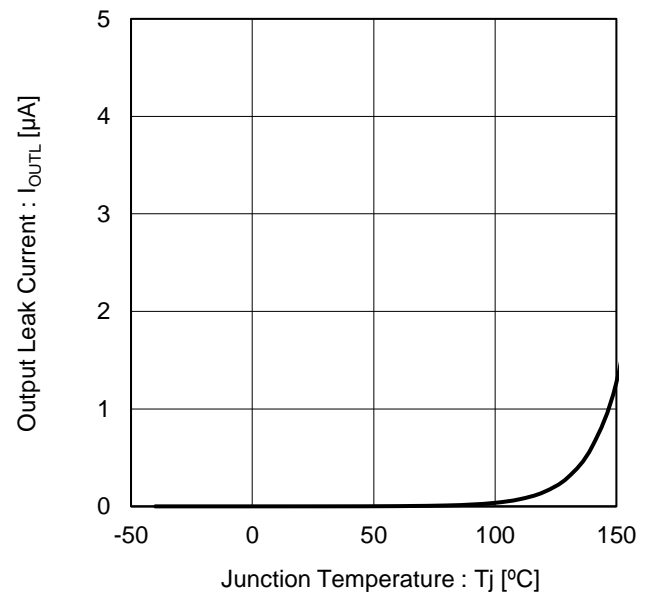


Figure 20. Output Leak Current vs Junction Temperature

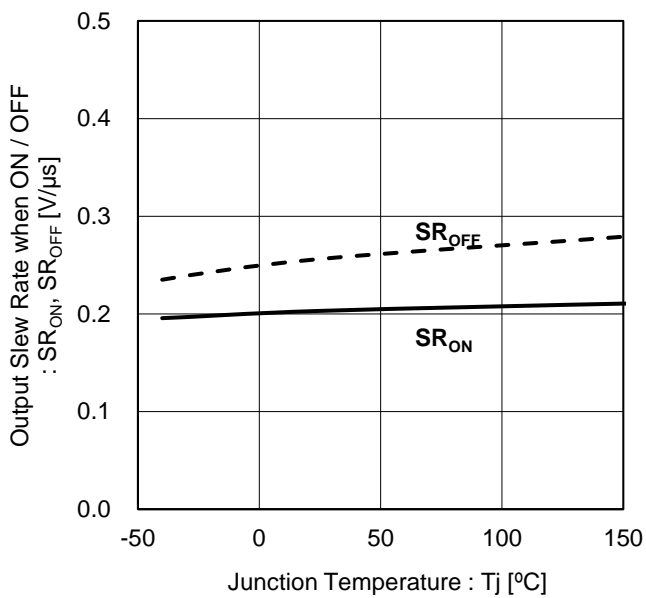


Figure 21. Output Slew Rate when ON / OFF vs Junction Temperature

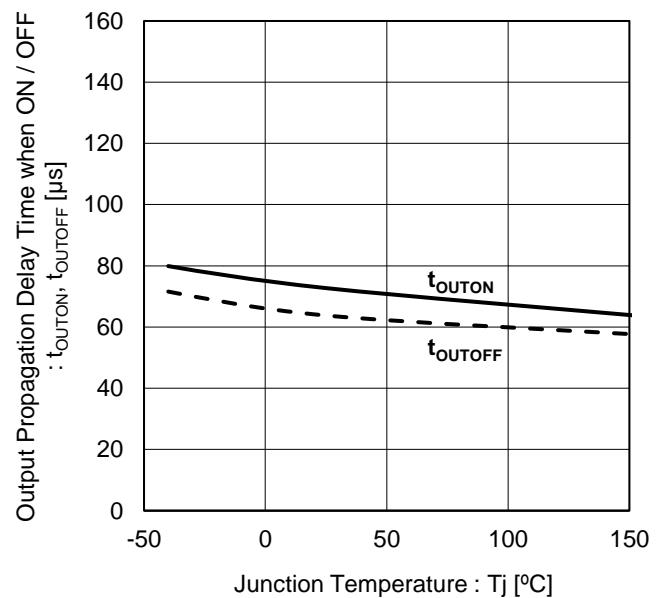


Figure 22. Output Propagation Delay Time when ON / OFF vs Junction Temperature



Typical Performance Curves - continued  
(Unless otherwise specified  $V_{BB} = 14\text{ V}$ ,  $V_{IN} = 5\text{ V}$ ,  $T_J = 25\text{ }^{\circ}\text{C}$ )

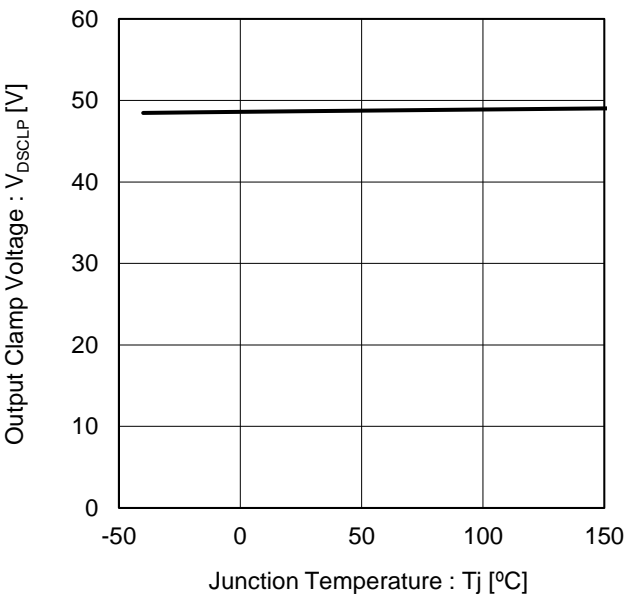


Figure 23. Output Clamp Voltage vs Junction Temperature

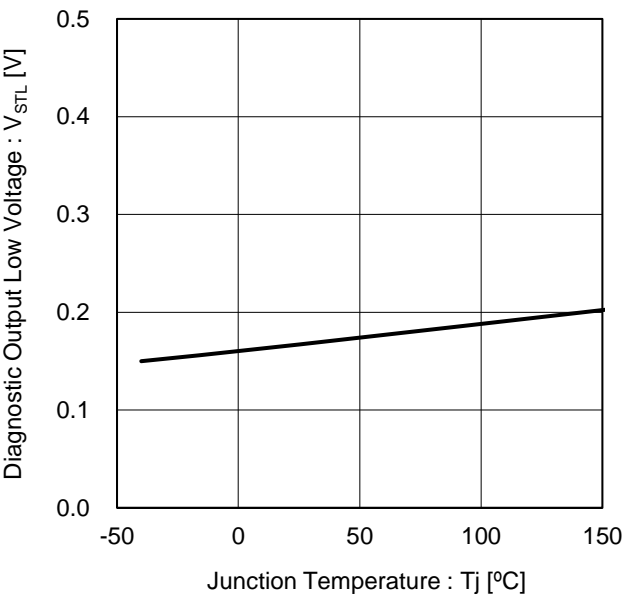


Figure 24. Diagnostic Output Low Voltage vs Junction Temperature

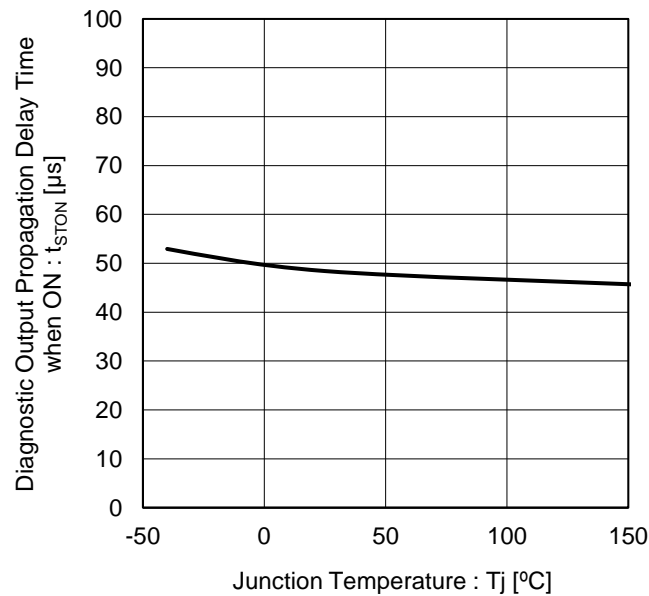


Figure 25. Diagnostic Output Propagation Delay Time when ON vs Junction Temperature

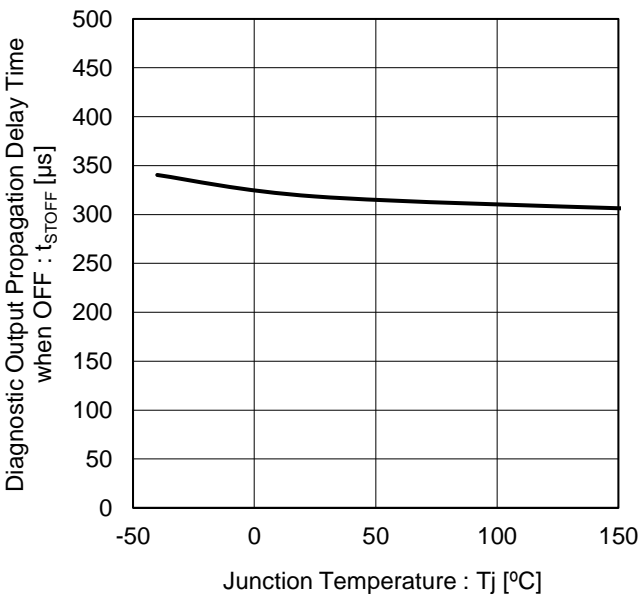


Figure 26. Diagnostic Output Propagation Delay Time when OFF vs Junction Temperature



Typical Performance Curves - continued

(Unless otherwise specified  $V_{BB} = 14\text{ V}$ ,  $V_{IN} = 5\text{ V}$ ,  $T_j = 25\text{ }^{\circ}\text{C}$ )

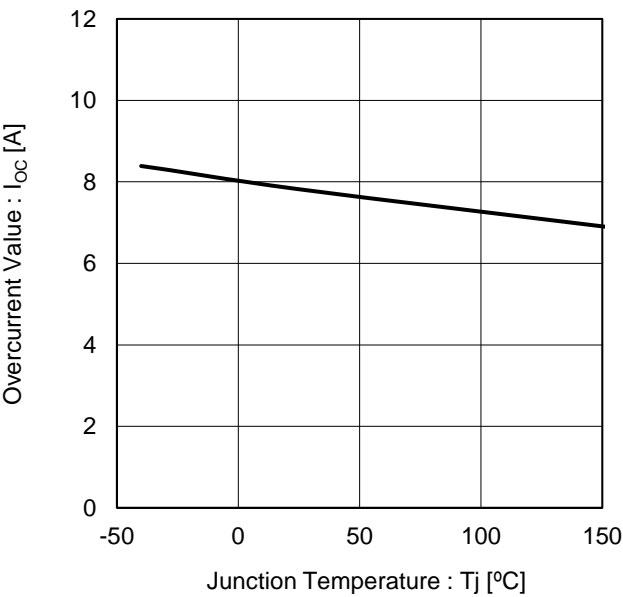


Figure 27. Overcurrent Value vs Junction Temperature

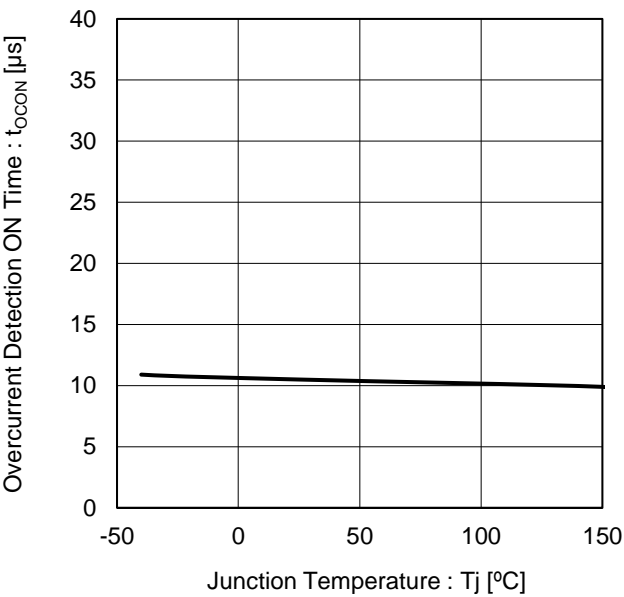


Figure 28. Overcurrent Detection ON Time vs Junction Temperature

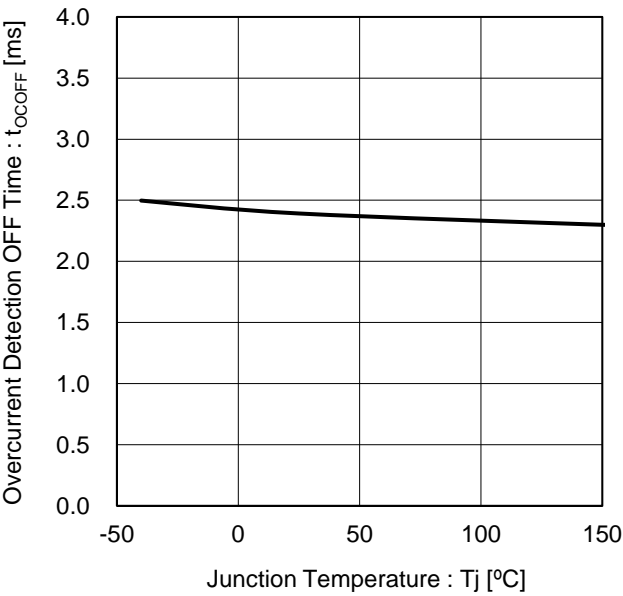


Figure 29. Overcurrent Detection OFF Time vs Junction Temperature

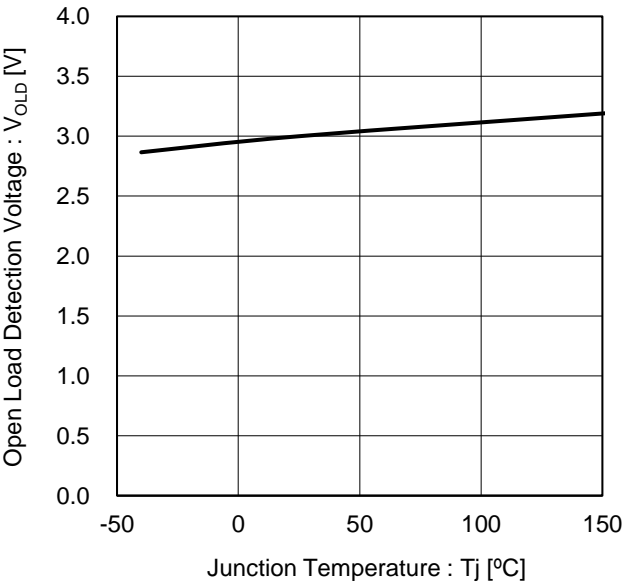


Figure 30. Open Load Detection Voltage vs Junction Temperature



Measurement Circuits

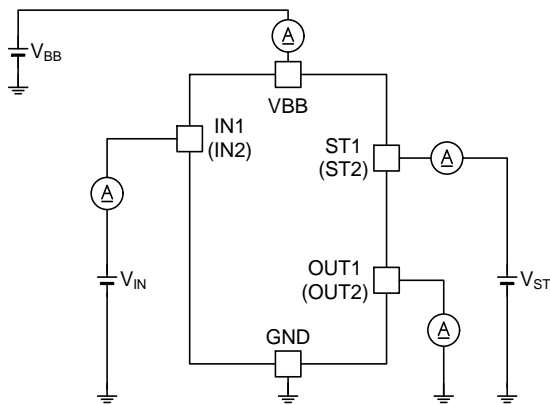


Figure 31. Standby Current  
Low Level Input Current  
Output Leak Current  
Diagnostic Output Leak Current

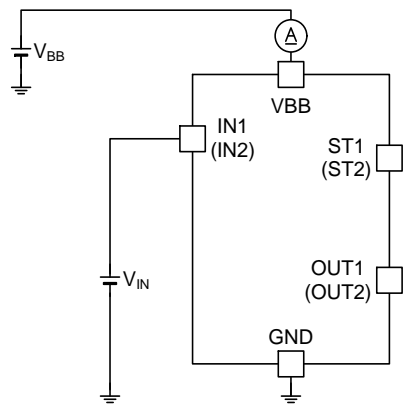


Figure 32. Operating Current

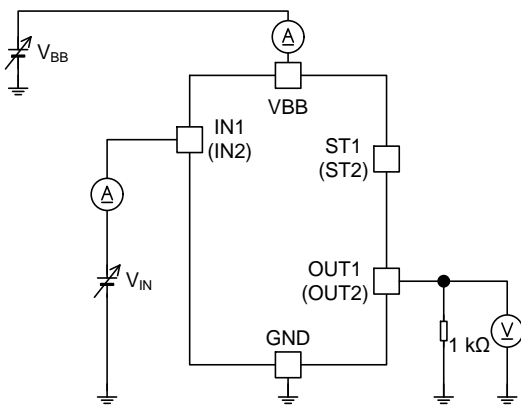


Figure 33. UVLO Detection / Hysteresis Voltage  
High / Low Level Input Voltage  
Input Hysteresis Voltage  
High Level Input Current  
Thermal Shutdown Detection  
/ Release / Hysteresis Temperature

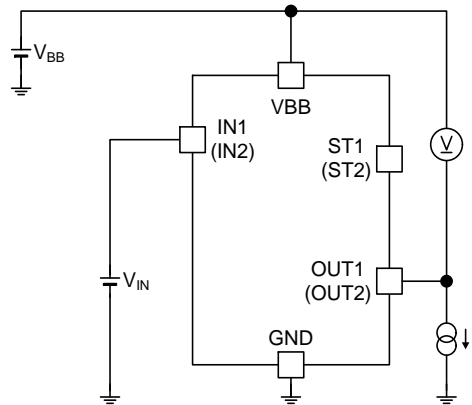


Figure 34. Output ON Resistance  
Output Clamp Voltage



Measurement Circuits - continued

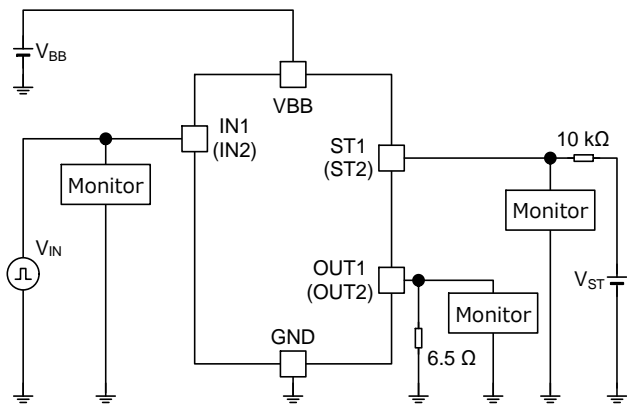


Figure 35. Output Slew Rate when ON / OFF  
Output Propagation Delay Time when ON / OFF  
Diagnostic Output Propagation Delay Time when ON

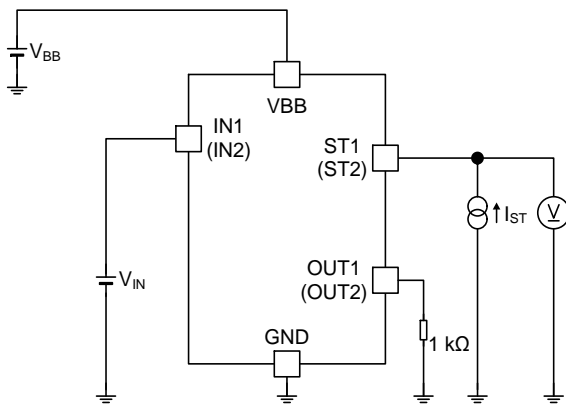


Figure 36. Diagnostic Output Low Voltage

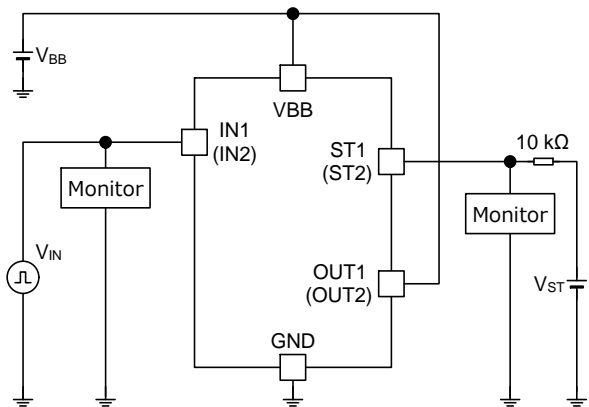


Figure 37. Diagnostic Output Propagation Delay Time when OFF

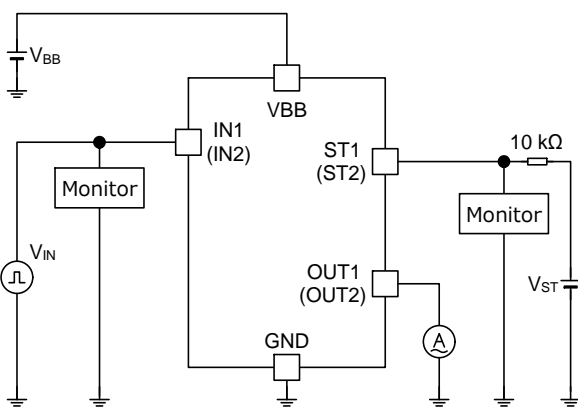


Figure 38. Overcurrent Value  
Overcurrent Detection ON / OFF Time



Measurement Circuits - continued

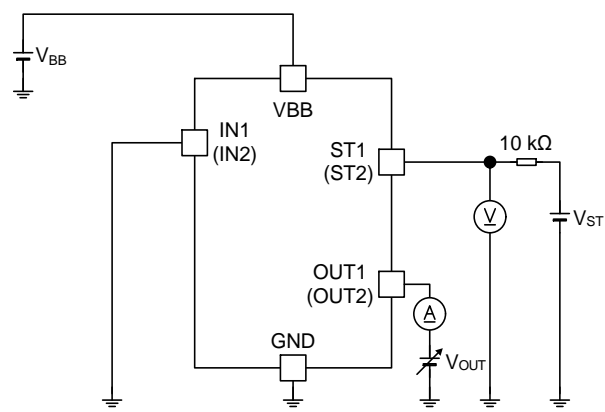


Figure 39. Open Load Detection Voltage  
Open Load Detection Sink Current



Measurement Conditions for Time Items

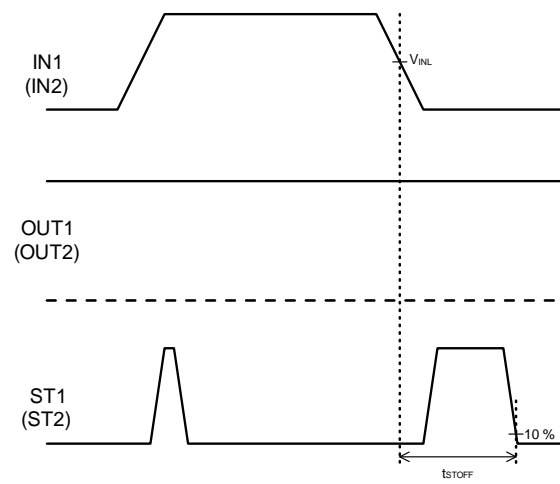
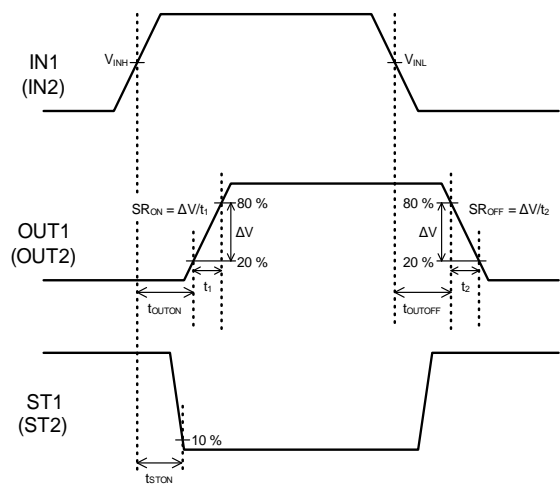


Figure 40. Output Slew Rate when ON / OFF  
Output Propagation Delay Time when ON / OFF  
Diagnostic Output Propagation Delay Time when ON

Figure 41. Diagnostic Output Propagation Delay Time when OFF

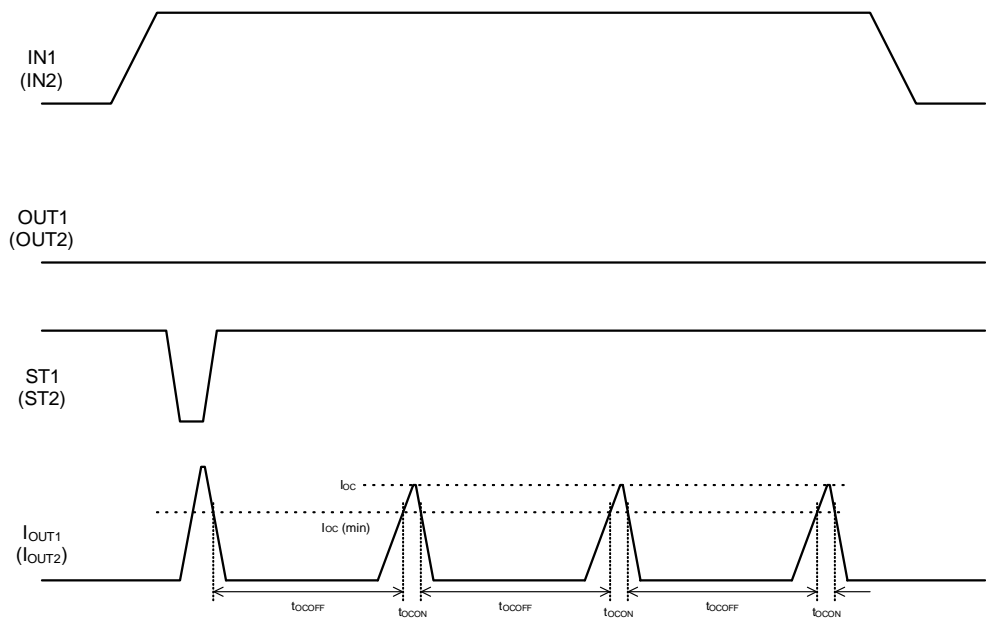


Figure 42. Overcurrent Value  
Overcurrent Detection ON / OFF Time



## Timing Chart

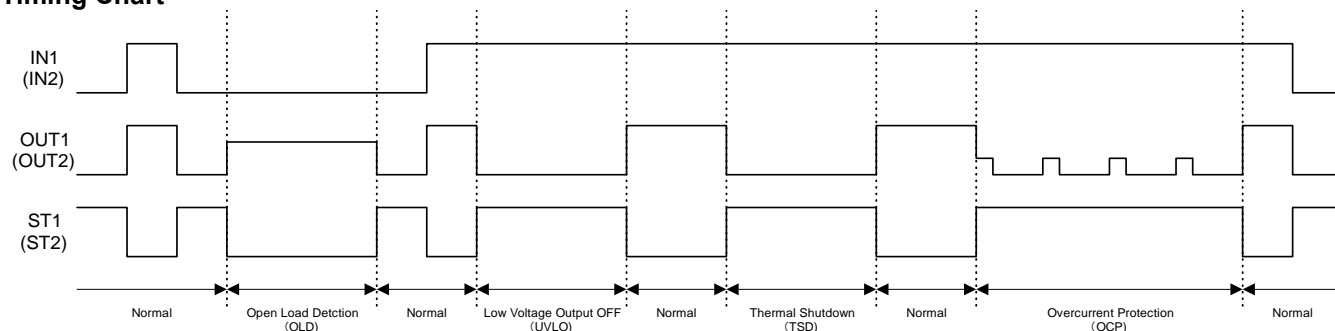


Figure 43. Timing Chart

## Description of Blocks

## 1. Protection Functions

Table 1. Detection and Release Conditions and Diagnostic Output of Each Protection Function<sup>(Note 1)</sup>

Mode		Detection / Release Conditions	Input Voltage $V_{INx}$	Diagnostic Output $V_{STx}$
Normal Condition	Standby	-	Low	High
	Operating	-	High	Low
Open Load Detect (OLD)		Detect $V_{OUTx} \geq 3.0 \text{ V (Typ)}$	Low	Low
		Release $V_{OUTx} \leq 2.2 \text{ V (Typ)}$	Low	High
Under Voltage Lockout (UVLO)		Detect $V_{BB} \leq 5.0 \text{ V (Max)}$	High	High
		Release $V_{BB} \geq 6.0 \text{ V (Max)}$	High	Low
Thermal Shutdown Protection (TSD) <sup>(Note 2)</sup>		Detect $T_j \geq 185 \text{ }^\circ\text{C (Typ)}$	High	High
		Release $T_j \leq 175 \text{ }^\circ\text{C (Typ)}$	High	Low
Overcurrent Protection (OCP)		Detect $I_{OUTx} \geq 6 \text{ A (Typ)}$	High	High
		Release $I_{OUTx} < 6 \text{ A (Typ)}$	High	Low

(Note 1)  $x = 1, 2$  and this is the same for  $x$  in the following sentence.

(Note 2) Thermal shutdown is automatically restored to normal operation.

This IC has a built-in protection detection function as mentioned above and outputs the condition with diagnostic output pin  $STx$ .

In normal condition, when input voltage  $V_{INx}$  is switched from Low to High, diagnostic output  $V_{STx}$  turns from High to Low. Inversely, when  $V_{INx}$  is switched from High to Low,  $V_{STx}$  turns from Low to High.

In protection function detected condition,  $V_{STx}$  is High when  $V_{INx}$  is High, and  $V_{STx}$  is Low when  $V_{INx}$  is Low. And after detecting protection function, this IC self-restarts and operation becomes normal if above release condition is satisfied.

## 2. Overcurrent Protection (Output ground fault detection)

This IC has a built-in hiccup mode overcurrent protection function. When the output pin ( $OUTx$ ) outputs overcurrent, the output of Channel  $x$  is turned off and diagnostic output  $V_{STx}$  becomes High. After Overcurrent Detection OFF Time ( $t_{OCOFF}$ ) from turn-off, output self-restarts and operation becomes normal if overcurrent doesn't flow. When overcurrent flows after the self-restart, output is turned off again. So, if the condition that causes overcurrent continues, output repeats ON and OFF periodically. And in this time  $V_{STx}$  keeps High.

And output current can exceed Overcurrent Value  $I_{OC}$  depending on the condition of impedance connected to  $V_{BB}$ ,  $OUT$  pins.

## 3. Thermal Shutdown Protection

This IC has a built-in thermal shutdown protection function. When the chip temperature of POWER-MOS unit for Channel  $x$  in this IC exceeds  $185 \text{ }^\circ\text{C (Typ)}$ , the output of Channel  $x$  is turned OFF and diagnostic output  $V_{STx}$  becomes High.

When the chip temperature of POWER-MOS unit for Channel  $x$  goes below  $175 \text{ }^\circ\text{C (Typ)}$ , output self-restarts and operation becomes normal.



## Description of Blocks - continued

## 4. Open Load Detection

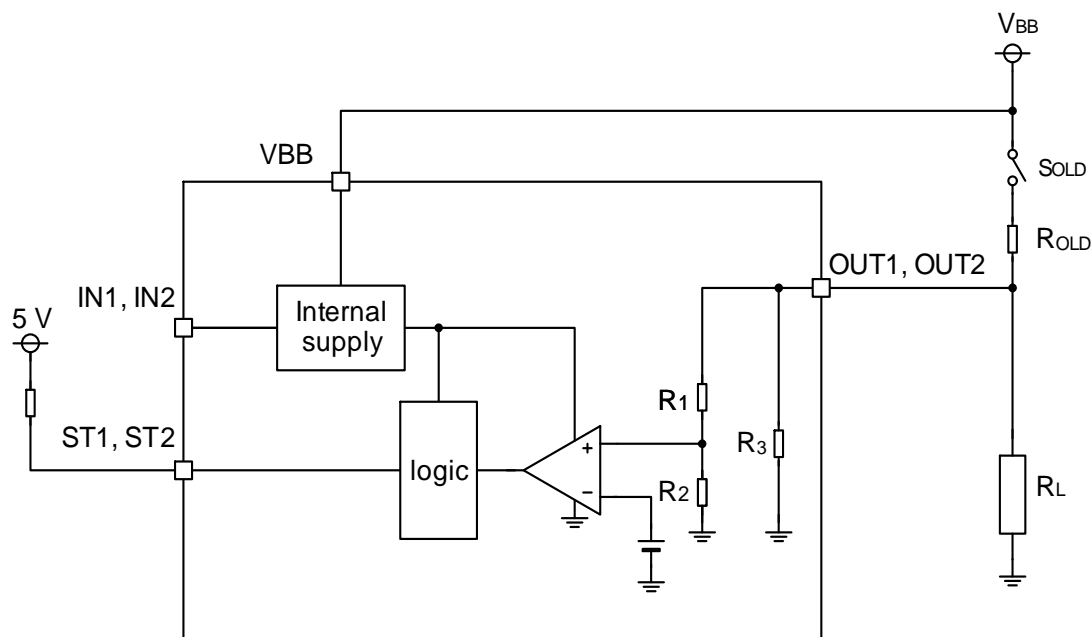


Figure 44. Open Load Detection Block Diagram

This IC has a built-in Open Load Detection function. By connecting an external resistance  $R_{OLD}$  between power supply pin ( $V_{BB}$ ) and output pin ( $OUTx$ ), when output load ( $R_L$ ) is disconnected during input voltage  $V_{INx}$  is Low, diagnostic output  $V_{STx}$  becomes Low.

To reduce the standby current of the system, inserting a switch  $S_{OLD}$  is recommended.

The value of  $R_{OLD}$  is decided based on below formula.

$$R_{OLD} < V_{BBMIN} \times 37.5 \times 10^3 - 150 \times 10^3 \text{ } [\Omega]$$

$$\left( = V_{BBMIN} \times \frac{R_{MIN}}{V_{OLDMAX}} - R_{MIN} \text{ } [\Omega] \right)$$

Where:

$V_{BBMIN}$  is the minimum value of power supply voltage ( $V_{BB}$ ).

$V_{OLDMAX}$  is the maximum value of Open Load Detection Voltage ( $V_{OLD}$ ).

$R_{MIN}$  is the minimum value of combined resistance of internal resistors  $R_1$ ,  $R_2$  and  $R_3$ .



## Description of Blocks - continued

## 5. Other Protection

## 5.1 GND Open Protection

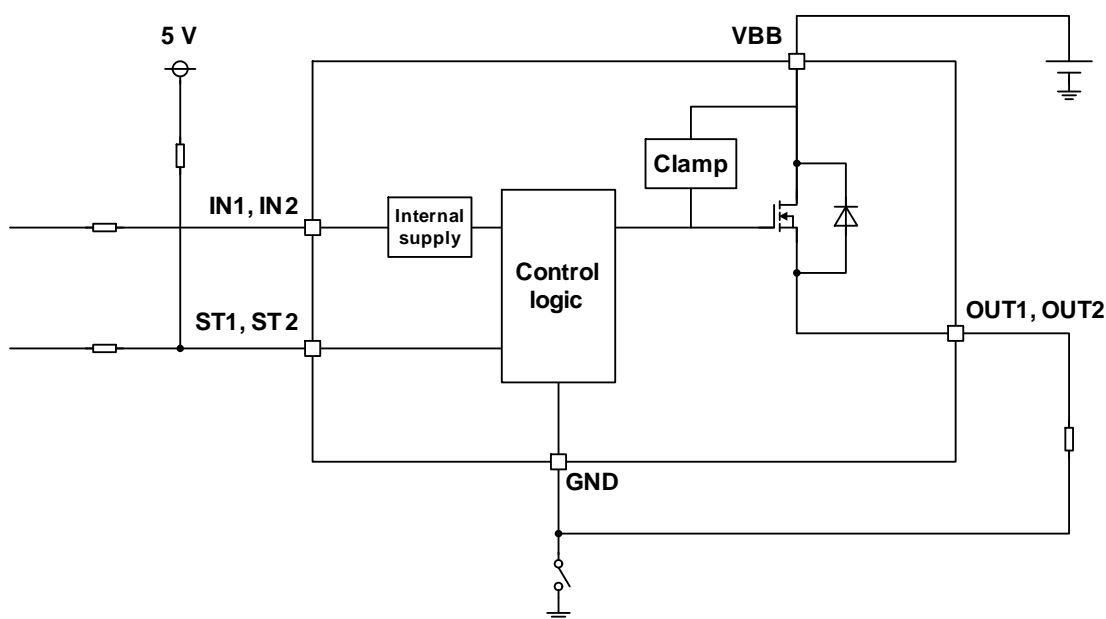


Figure 45. GND Open Protection Block Diagram

When GND of the IC is open, the output is switched OFF regardless of the input voltage  $V_{INx}$ . However, diagnostic output  $V_{STx}$  is not flagged.

The active clamp operates when GND become open during driving inductive load.

## 5.2 MCU I/O Protection

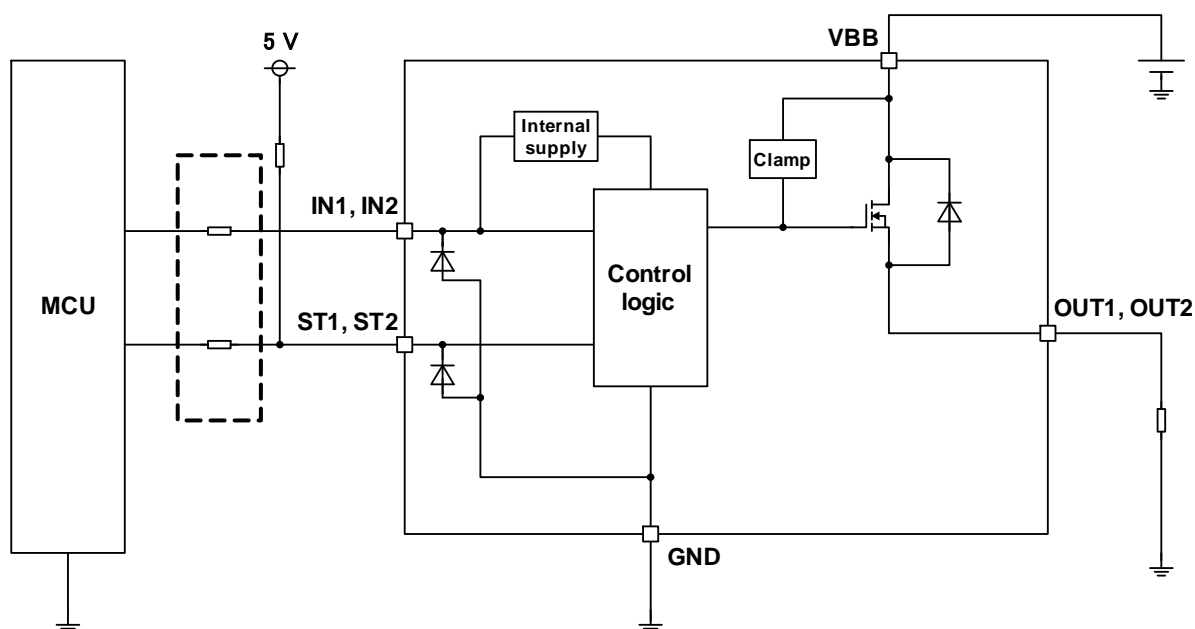
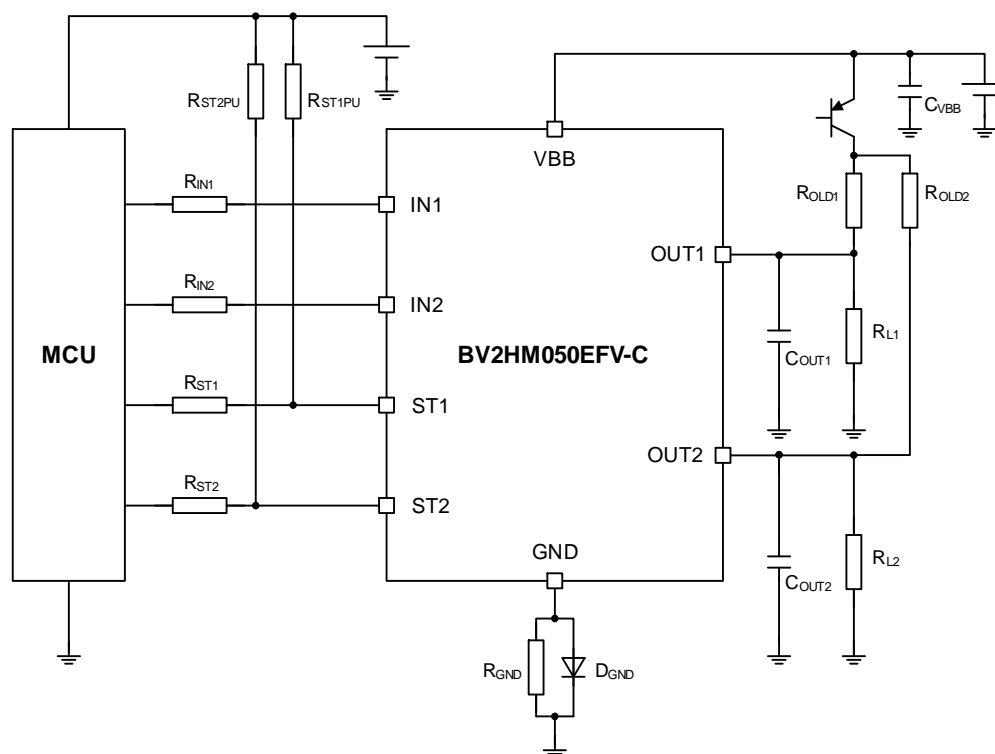


Figure 46. MCU I/O Protection Diagram

Negative surge voltage to input pin (IN1, IN2) or diagnostic output pin (ST1, ST2) may cause damage to the MCU's I/O pins. In order to prevent those damages, it is recommended to insert limiting resistors between IC pins and MCU.



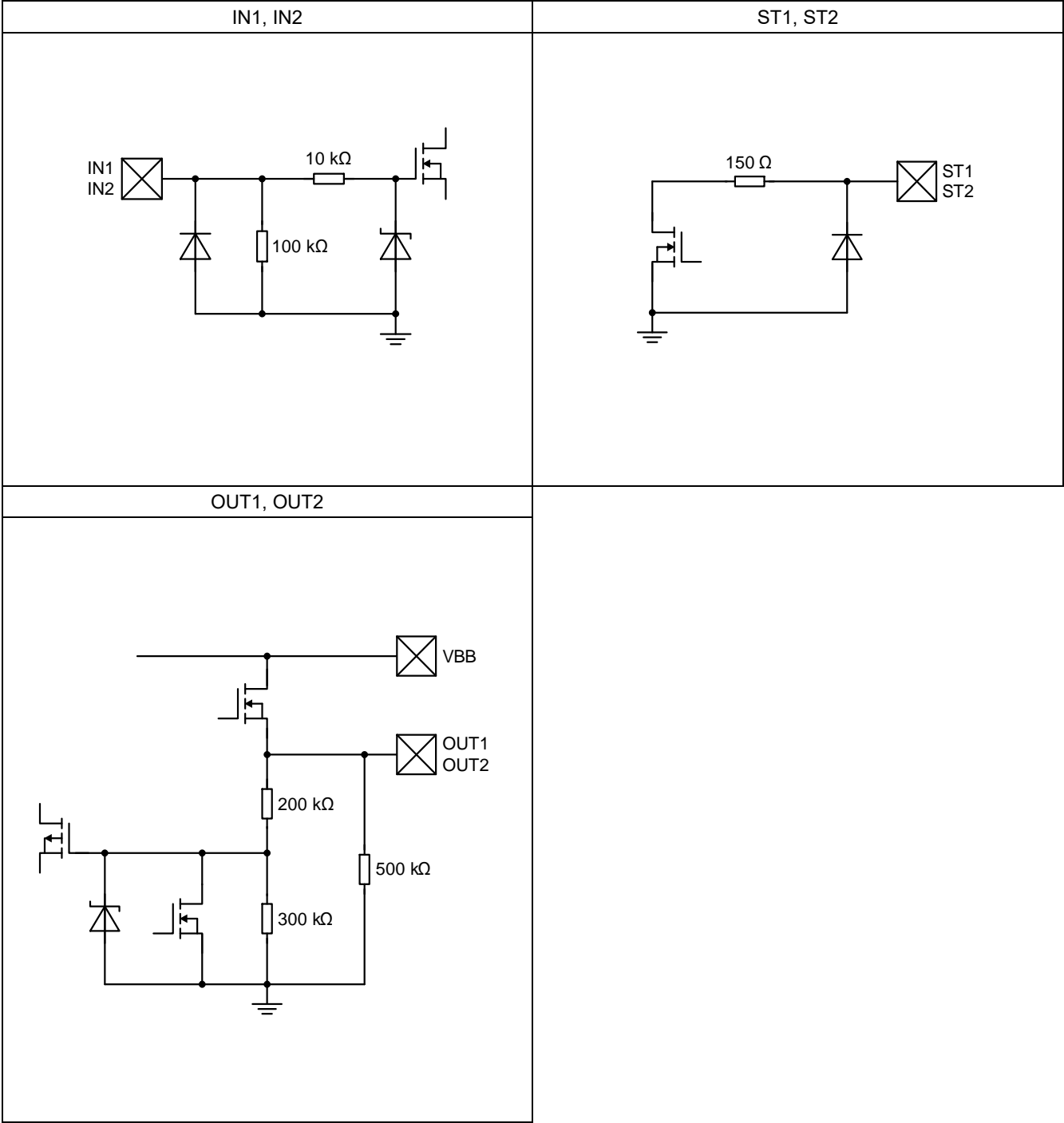
## Applications Example



Symbol	Value	Purpose
$R_{IN1}, R_{IN2}$	1 k $\Omega$	Limit resistance for negative surge
$R_{ST1}, R_{ST2}$	1 k $\Omega$	Limit resistance for negative surge
$R_{ST1PU}, R_{ST2PU}$	10 k $\Omega$	Pull up resistance for diagnostic output The ST1 and ST2 pins are open drain output and pull up these pins to MCU power supply.
$C_{VBB}$	10 $\mu$ F	Filter for battery line voltage spike
$R_{GND}$	1 k $\Omega$	Current limit resistance for reverse battery connection
$D_{GND}$	-	Protection diode for BV2HM050EFV-C against reverse battery connection
$R_{OLD1}, R_{OLD2}$	2 k $\Omega$	Resistance for open load detection
$C_{OUT1}, C_{OUT2}$	1000 pF	Filter for radiation noise from outside of BV2HM050EFV-C
$R_{L1}, R_{L2}$	-	Output load



I/O Equivalence Circuits





## Operational Notes

### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

### 3. Ground Voltage

Except for pins the output and the input of which were designed to go below ground, ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

### 5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

### 6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

### 7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

### 8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

### 9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

### 10. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

### 11. Thermal Shutdown Function (TSD)

This IC has a built-in thermal shutdown function that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature ( $T_j$ ) will rise which will activate the TSD function that will turn OFF power output pins. When the  $T_j$  falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD function operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD function be used in a set design or for any purpose other than protecting the IC from heat damage.



**Operational Notes – continued****12. Over Current Protection Function (OCP)**

This IC incorporates an integrated overcurrent protection function that is activated when the load is shorted. This protection function is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection function.

**13. Active Clamp Operation**

The IC integrates the active clamp function to internally absorb the reverse energy  $E_L$  which is generated when the inductive load is turned off. When the active clamp operates, the thermal shutdown function does not work. Decide a load so that the reverse energy  $E_L$  is active clamp energy  $E_{AS}$  (refer to Figure 5. Active Clamp Energy vs Output Current) or under when inductive load is used.

**14. Open Power Supply Pin**

When the power supply pin (VBB) becomes open at ON (IN = High), the output is switched to OFF regardless of input voltage. If an inductive load is connected, the active clamp operates when VBB is open and becomes the same potential as that on the ground. At this time, the output voltage drops down to -48 V (Typ).

**15. Open GND Pin**

When the GND pin becomes open at ON (IN = High), the output is switched to OFF regardless of input voltage. If an inductive load is connected, the active clamp operates when the GND pin is open.

**16. OUT Pin Voltage**

Ensure that keep OUT pin voltage less than ( $V_{BB} + 0.3\text{ V}$ ) at any time, even during transient condition. And ensure that OUT pin voltage is more than ( $GND - 0.3\text{ V}$ ) when this IC is turned ON. Otherwise malfunction or other problems can occur.

**17. Same Pin Connection**

Connect all VBB pins, GND pins, OUT1 pins, OUT2 pins to same line respectively.

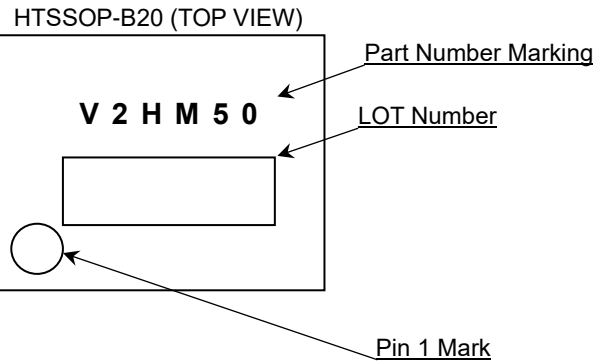


Ordering Information

B	V	2	H	M	0	5	0	E	F	V	-	C	E	2
---	---	---	---	---	---	---	---	---	---	---	---	---	---	---

Part Number	Package EFV: HTSSOP-B20	Product Rank C: Automotive product Packaging and Forming Specification E2: Embossed tape and reel
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Marking Diagram

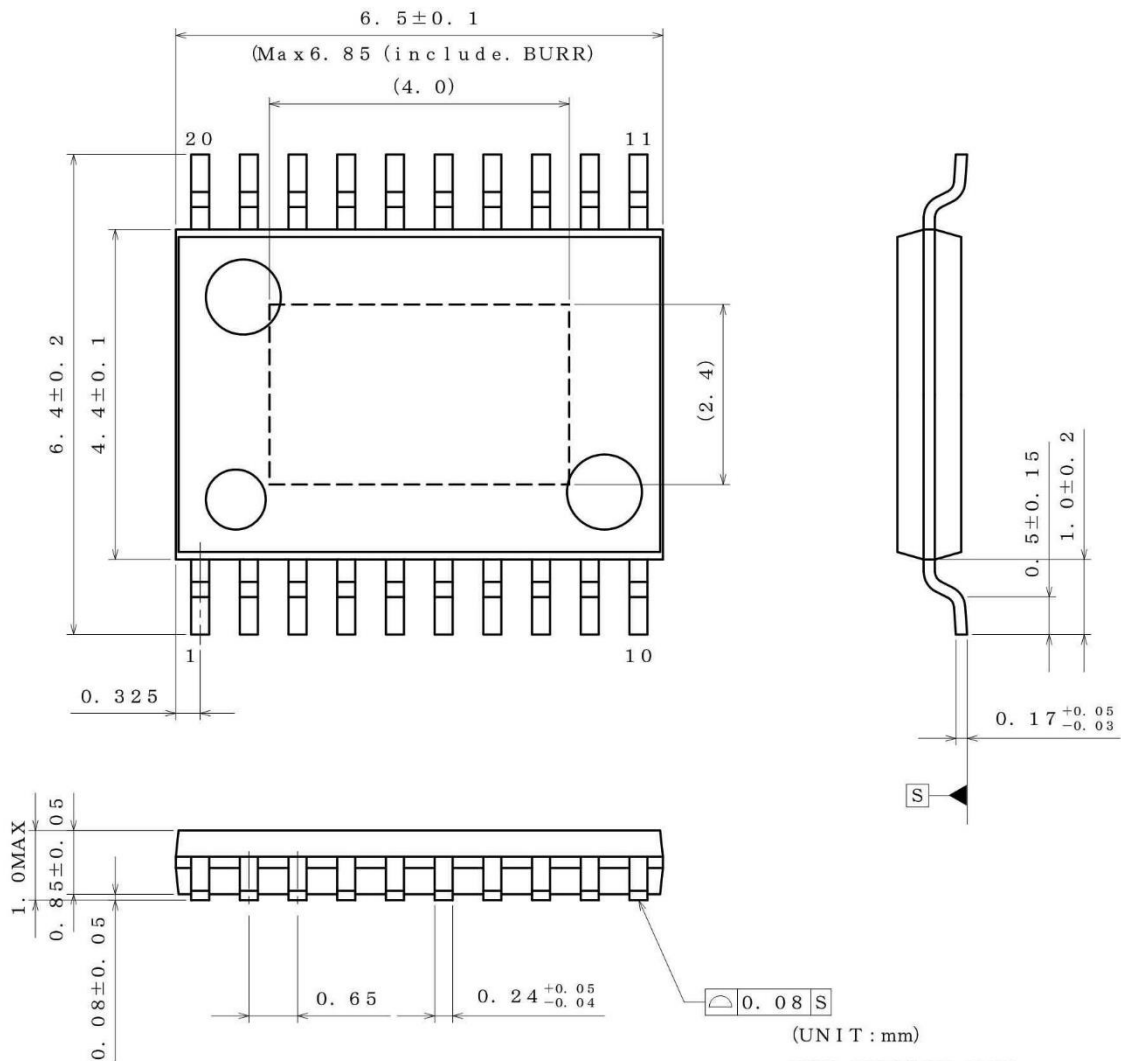




## Physical Dimension and Packing Information

Package Name

HTSSOP-B20

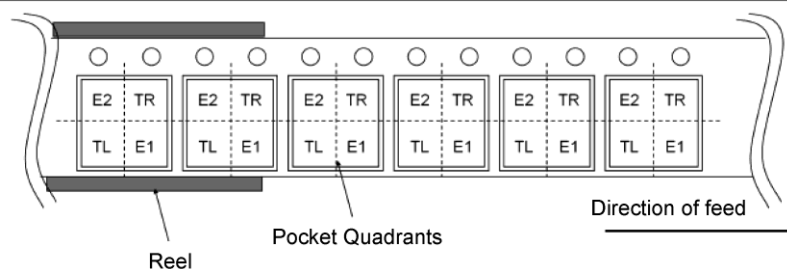


PKG : HTSSOP-B20

Drawing No. EX192-5002

## &lt; Tape and Reel Information &gt;

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 The direction is the pin 1 of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand





## Revision History

Date	Revision	Changes
20.Jan.2022	001	New Release
31.Oct.2022	002	Page.27 Ordering Information The Description of "Part Number" is added.



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JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

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5. Please verify and confirm characteristics of the final or mounted products in using the Products.
6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
8. Confirm that operation temperature is within the specified range described in the product specification.
9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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For details, please refer to ROHM Mounting specification



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4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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